MASW-002102-13580 MASW-003102-13590

HMIC[™] Silicon PIN Diode Switches with Integrated Bias Network



Rev. V5

Features

- Broad Bandwidth Specified up to 18 GHz
- Usable up to 26 GHz
- Integrated Bias Network
- Low Insertion Loss / High Isolation
- Rugged
- Fully Monolithic
- Glass Encapsulate Construction
- RoHS Compliant* and 260°C Reflow Compatible

Description

The MASW-002102-13580 and MASW-003102-13590 devices are SP2T and SP3T broad band switches with integrated bias networks utilizing M/A-COM Technology Solutions HMIC[™] (Heterolithic Microwave Integrated Circuit) process, US Patent 5,268,310. This process allows the incorporation of silicon pedestals that form series and shunt diodes or vias by imbedding them in low loss, low dispersion glass. By using small spacing between elements, this combination of silicon and glass gives HMIC devices low loss and high isolation performance with exceptional repeatability through low millimeter frequencies. Large bond pads facilitate the use of low inductance ribbon bonds, while gold backside metallization allows for manual or automatic chip bonding via 80/20 - Au/Sn, 62/36/2 - Sn/Pb/Ag solders or electrically conductive silver epoxy.

Parameter	Absolute Maximum
Operating Temperature	-65°C to +125°C
Storage Temperature	-65°C to +150°C
Junction Temperature	+175°C
Applied Reverse Voltage	50V
RF Incident Power	+33dBm C.W.
Bias Current +25°C	±20mA

Max. operating conditions for a combination of RF power, D.C. bias and temperature:

+33dBm CW @ 15mA (per diode) @+85°C

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MASW-002102-13580



MASW-003102-13590



Yellow areas denote wire bond pads

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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Electrical Specifications @ T _{AMB} = +25°C, 20mA Bias current					
Parameter	Frequency	Minimum	Nominal	Maximum	Units
	2 GHz		1.5	1.8	dB
Insertion Loss	6 GHz		0.70	1.0	dB
Insertion Loss	12 GHz		0.90	1.2	dB
	18 GHz		1.2	1.8	dB
	2 GHz	55	60		dB
	6 GHz	47	50		dB
Isolation	12 GHz	40	45		dB
	18 GHz	36	40		dB
	2 GHz		14		dB
Input Return Loss	6 GHz		15		dB
	12 GHz		15		dB
	18 GHz		13.0		dB
Switching Speed ¹	-		50		ns

MASW-002102-13580 (SPDT) Electrical Specifications @ T_{AMB} = +25°C, 20mA Bias curren

MASW-003102-13590 (SP3T) Electrical Specifications @ T_{AMB} = +25°C, 20mA Bias current

Parameter	Frequency	Minimum	Nominal	Maximum	Units
	2 GHz		1.6	2.0	dB
Insertion Loss	6 GHz		0.8	1.1	dB
Insertion Loss	12 GHz		1.0	1.3	dB
	18 GHz		1.3	1.9	dB
	2 GHz	54	59		dB
	6 GHz	47	50		dB
Isolation	12 GHz	40	45		dB
	18 GHz	36	40		dB
	2 GHz		14		dB
Innut Poturn Loco	6 GHz		15		dB
Input Return Loss	12 GHz		16		dB
	18 GHz		14		dB
Switching Speed ¹	-		50		ns

Note:

1. Typical switching speed measured from 10% to 90% of detected RF signal driven by TTL compatible drivers using RC output spiking network, R = $50 - 200\Omega$, C = 390 - 560pF.

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INSERTION LOSS vs FREQUENCY MASW-002102-13580



Typical RF Performance at $T_A = +25$ °C, 20mA Bias Current







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Note:

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0.10

0.00

The PIN diodes in the MASW-002102-13580 and the MASW-003102-13590 have the same electrical characteristics and will have similar performance.

20.00

25.00

C.W. Incident Power (dBm)

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15.00

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30.00

35.00

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Operation of the MASW-002102-13580 and MASW-003102-13590

Operation of the MASW-002102-13580 and MASW-003102-13590 PIN diode switches is achieved by simultaneous application of DC currents to the bias pads. The required levels for the different states are shown in the tables below. The on-chip pull-up resistor @ J1, shown in the schematic below, has a value of $40\Omega - 60\Omega$ and must be taken into consideration when defining drive circuitry.

Driver Connections MASW-002102-13580

Control Level I _{DC} @		Condition of RF Output	Condition of RF Output
J4	J5	J1 - J2	J1 - J3
-20mA	+20mA	Low Loss	Isolation
+20mA	-20mA	Isolation	Low Loss

Driver Connections MASW-003102-13590

Co	Control Level I _{DC} @		Condition of RF Output	Condition of RF Output	of
J5	J6	J7	J1 - J2	J1 - J3	J1 - J4
-20mA	+20mA	+20mA	Low Loss	Isolation	Isolation
+20 mA	-20mA	+20mA	Isolation	Low Loss	Isolation
+20mA	+20mA	-20mA	Isolation	Isolation	Low Loss

Equivalent Circuit MASW-002102-13580



Equivalent Circuit MASW-003102-13590



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Wire/Ribbon and Die Attachment Recommendations

Wire Bonding

Thermosonic wedge wire bonding using 0.00025" x 0.003" ribbon or 0.001" diameter gold wire is recommended. A heat stage temperature of 150°C and a force of 18 to 22 grams should be used. Ultrasonic energy should be adjusted to the minimum required to achieve a good bond. RF bond wires should be kept as short and straight as possible.

Chip Mounting

The HMIC switches have Ti-Pt-Au back metal. They can be die mounted with a gold-tin eutectic solder preform or conductive epoxy. Mounting surface must be clean and flat.

*Note: This device utilizes a process step designed to have minimal to non-existent burring around the perimeter of the die.

Eutectic Die Attachment: An 80/20, gold-tin, eutectic solder preform is recommended with a work surface temperature of 255°C and a tool tip temperature of 265°C. When hot gas is applied, the tool tip temperature should be 290°C. The chip should not be exposed to temperatures greater than 320°C for more than 20 seconds. No more than three seconds should be required for attachment. Solders containing tin should not be used.

Epoxy Die Attachment: A minimum amount of epoxy should be used. A thin epoxy fillet should be visible around the perimeter of the chip after placement. Cure epoxy per manufacturer's schedule (typically 125-150°C).



MASW-002102-13580 Chip Outline Drawing^{1,2}

- Notes:
- Topside and backside metallization is gold, 2.5um thick typical. 1.
- 2. Yellow areas indicate wire bonding pads

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MASW-003102-13590 Chip Outline Drawing^{1,2}

DIM	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
А	0.0697	0,0736	1.770	1.870
В	0.0693	0.0732	1.760	1.860
С	0.0039	0.0059	0.100	0.150
D	0.0310	0.0319	0.787	0.812
E	0.0289	0.0299	0.734	0.759
F	0.0055	0.0075	0.140	0.190
G	0.0035	0.0055	0.089	0.139
Н	0.0044	0.0064	0.113	0.163
J	0.0338	0.0358	0.859	0.909
К	0.0632	0.0652	1.610	1.660
L	0.0660	0.0680	1.680	1.730
М	0.0051	REF.	0.1290	REF.
N	0.0046	REF.	0.1180	REF.

Notes:

- 1. Topside and backside metallization is gold , 2.5um thick typical.
- 2. Yellow areas indicate wire bonding pads

Ordering Information

Part Number	Package
MASW-002102-13580G	Gel Pack (25 per)
MASW-002102-13590W	Waffle Pack (25 per)
MASW-003102-13590G	Gel Pack (25 Per)
MASW-003102-13590W	Waffle Pack (25 Per)

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